TOSHIBA TB2996HQ

Bi-CMOS Linear Integrated Circuit Silicon Monolithic

# **TB2996HQ**

# Maximum Power 49 W BTL × 4ch Audio Power Amp IC

# 1. Description

The TB2996HQ is a power IC with built-in four-channel BTL amplifier developed for car audio application. The maximum output power  $P_{\rm OUT}$  is 49 W using a pure complementary P-ch and N-ch DMOS output stage.

In addition, a standby switch, a mute function, output offset voltage detector and various protection features are included.

# HZIP25-P-1.00F

Weight: 7.7 g (typ.)

# 2. Applications

Power Amp IC developed for car audio applications.

### 3. Features

- High output power, low distortion, and low noise property (for details, refer to the Table 1 Typical Characteristics).
- Built-in detecting output offset voltage and shorted to GND (Pin25)
- Built-in muting function. (Pin22)
- Built-in auto muting functions (for low Vcc and stand-by sequence)
- Built-in standby switch. (Pin4)
- Built-in 6v operation and start stop cruising circuit
- Built-in various protection circuits (thermal shut down, over-voltage, short to GND, short to VCC, and output to output short)

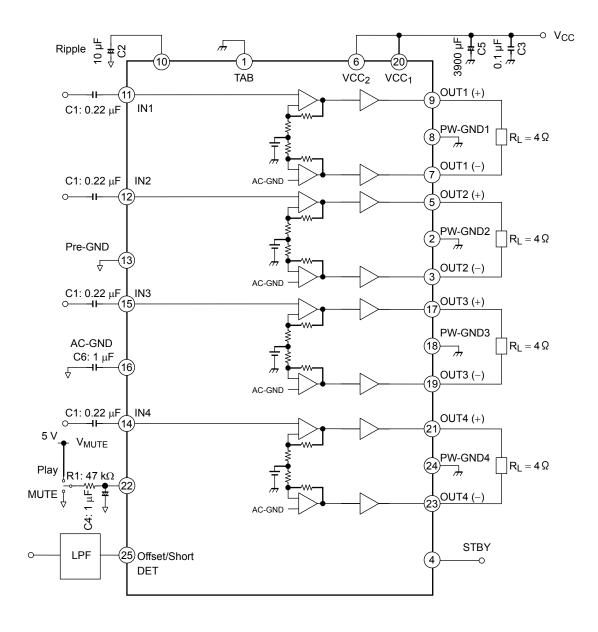
Table 1 Typical Characteristics (Note1)

| Test condition                                     | Тур.  | Unit |  |  |  |  |  |
|--|-------|------|--|--|--|--|--|
| Output power (P <sub>OUT</sub> )                   |       |      |  |  |  |  |  |
| V <sub>CC</sub> = 15.2 V, JEITA max                | 49    |      |  |  |  |  |  |
| V <sub>CC</sub> = 14.4V, JEITA max                 | 44    | ۱۸/  |  |  |  |  |  |
| V <sub>CC</sub> = 14.4V,THD = 10%                  | 29    | W    |  |  |  |  |  |
| THD = 10%  | 24    |      |  |  |  |  |  |
| Total harmonic distortion (THD)                    |       |      |  |  |  |  |  |
| P <sub>OUT</sub> = 4 W                             | 0.006 | %    |  |  |  |  |  |
| Output noise voltage $(V_{NO})$ (Rg = 0 $\Omega$ ) |       |      |  |  |  |  |  |
| Filter : DIN AUDIO                                 | 50    | μV   |  |  |  |  |  |
| Operating Supply voltage range (V <sub>CC</sub> )  |       |      |  |  |  |  |  |
| R <sub>L</sub> = 4 Ω                               | 6~18  |      |  |  |  |  |  |
| R <sub>L</sub> = 2 Ω                               | 6~16  | ٧    |  |  |  |  |  |

Note1: Typical test conditions :  $V_{CC}$  = 13.2 V, f = 1 kHz,  $R_L$  = 4  $\Omega$ ,  $G_V$  = 26 dB,  $T_a$  = 25°C; unless otherwise specified.

Note2: Rg = signal source resistance

# 4. Block Diagram

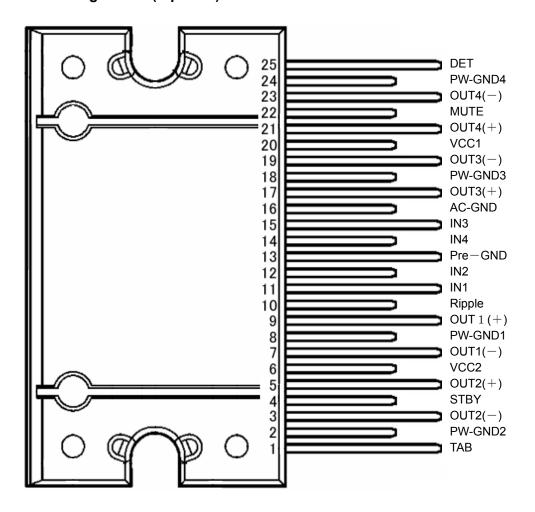


Some of the functional blocks, circuits or constants labels in the block diagram may have been omitted or simplified for clarity.

In the following explanation, a "channel" is a circuit which consists of INx, OUTx (+), OUTx (-), and PW-GNDx. (x:1 to 4)

# 5. Pin Configuration and Function Descriptions

5.1 Pin Configuration (top view)

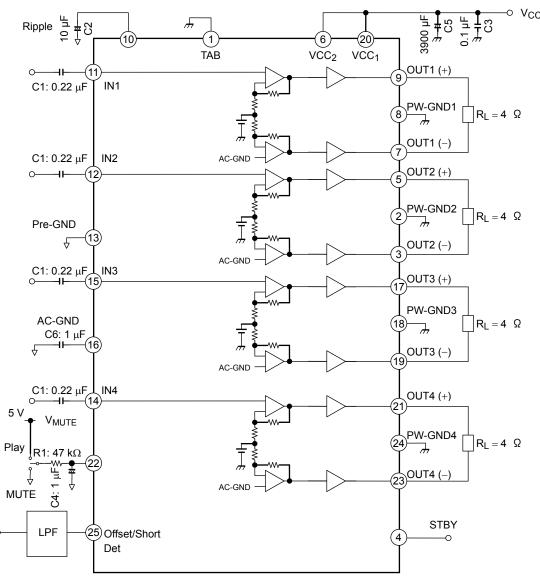


# 5.2 Pin Function Descriptions

| Pin | Symbol           | I/O                  | Description  |
|-----|------------------|----------------------|--|
| 1   | TAB              | _                    | Ground (TAB)                                       |
| 2   | PW-GND2          | _                    | Ground for OUT2                                    |
| 3   | OUT2(-)          | OUT                  | OUT2(-) output                                     |
| 4   | STBY             | V <sub>ST</sub> -IN  | Standby voltage input                              |
| 5   | OUT2(+)          | OUT                  | OUT2(+) output                                     |
| 6   | VCC <sub>2</sub> | V <sub>CC</sub> -IN  | Supply voltage 2                                   |
| 7   | OUT1(-)          | OUT                  | OUT1(-) output                                     |
| 8   | PW-GND1          | _                    | Ground for OUT1                                    |
| 9   | OUT1(+)          | OUT                  | OUT1(+) output                                     |
| 10  | Ripple           |                      | Ripple voltage                                     |
| 11  | IN1              | IN                   | OUT1 input   |
| 12  | IN2              | IN                   | OUT2 input   |
| 13  | Pre-GND          | _                    | Signal ground                                      |
| 14  | IN4              | IN                   | OUT4 input   |
| 15  | IN3              | IN                   | OUT3 input   |
| 16  | AC-GND           | _                    | Common reference voltage for all input             |
| 17  | OUT3(+)          | OUT                  | OUT3(+) output                                     |
| 18  | PW-GND3          |                      | Ground for OUT3                                    |
| 19  | OUT3(-)          | OUT                  | OUT3(-) output                                     |
| 20  | VCC <sub>1</sub> | V <sub>CC</sub> -IN  | Supply voltage 1                                   |
| 21  | OUT4(+)          | OUT                  | OUT4(+) output                                     |
| 22  | MUTE             | V <sub>mute</sub> IN | Mute voltage input                                 |
| 23  | OUT4(-)          | OUT                  | OUT4(-) output                                     |
| 24  | PW-GND4          | _                    | Ground for OUT4                                    |
| 25  | DET              | (OC) Note1           | Offset detector output / Out to GND short detector |

Note1:OC means are open collector output

# 6. Functional Description



| Component | Recommended | Pin                                    | Durnaga                                  | Effect   | (Note1)                       |  |
|-----------|-------------|--|--|--|-------------------------------|--|
| Name      | Value       | PIII                                   | Purpose                                  | Lower than Recommended Value                             | Higher than Recommended Value |  |
| C1        | 0.22 μF     | INx<br>(x:1 to 4)                      | To eliminate DC                          | Cut-off frequency becomes higher                         |                               |  |
| C2        | 10 μF       | Ripple                                 | To reduce ripple                         | Turn on/off time shorter Turn on/off time longer         |                               |  |
| C3        | 0.1 μF      | VCC <sub>1,</sub><br>VCC <sub>2</sub>  | To provide sufficient oscillation margin | Reduces noise and provides sufficient oscillation margin |                               |  |
| C6        | 1 μF        | AC-GND                                 | Common reference voltage for all input   | Pop noise is suppressed when C1: C6 = 1:4. (Note2)       |                               |  |
| C5        | 3900 μF     | VCC <sub>1</sub> ,<br>VCC <sub>2</sub> | Ripple filter                            | Power supply ripple filtering                            |                               |  |
| R1 / C4   | 47kΩ / 1 μF | MUTE                                   | Mute ON/OFF<br>Smooth switching          | Pop noise becomes larger                                 | Switching time becomes longer |  |

Note1: When the unrecommended value is used, please examine it enough by system evaluation.

Note2: Since "AC-GND" pin is a common reference voltage for all input, this product needs to set the ratio of an input capacitance (C1) and the AC-GND capacitance (C6) to 1:4

Note3: Use the low leak current capacitor for C1 and C6.

# 7. Standby Function (Pin 4)

The power supply can be turned on or off via pin 4 (STBY). The threshold voltage of pin 4 is below table. The power supply current is about 0.01  $\mu A$  (typ.) in the standby state.

### Standby Control Voltage (V<sub>SB</sub>): Pin 4

| STBY | Power | V <sub>SB</sub> (V) |
|------|-------|---------------------|
| ON   | OFF   | 0~0.9               |
| OFF  | ON    | 2.2~V <sub>CC</sub> |

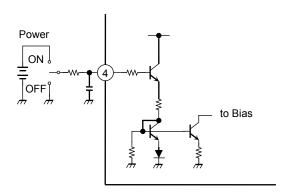


Figure 1 Internal circuit for standby

### Benefits of the Standby Switch

VCC can be directly turned on or off by a microcontroller, eliminating the need for a switching relay. Since the control current is minuscule, a low-current-rated switching relay can be used.

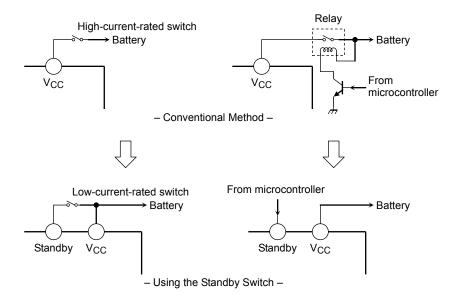


Figure 2 Standby Switch

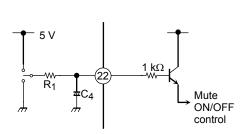
# 8. Mute Function (pin 22)

The audio mute function is enabled by setting pin 22 Low. R<sub>1</sub> and C<sub>4</sub> determine the time constant of the mute function. The time constant affects pop noise generated when power or the mute function is turned on or off; thus, it must be determined on a per-application basis. (Refer to Figures 3 and 4.)

The value of the external pull-up resistor is determined, based on pop noise value.

### $For \ example :$

when the control voltage is changed from 5V to 3.3V, the pull-up resistor should be:  $3.3V/5V\times47~k\Omega=31k\Omega$ 



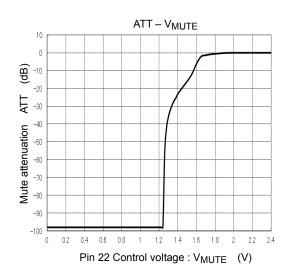


Figure 3 Mute Function

Figure 4 Mute Attenuation - V<sub>MUTE</sub> (V)

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# 9. Auto Muting Functions

The TB2996HQ has two automatic mute function.

- a) Low Vcc Mute
- b) Stand-by Off Mute.

### 9.1 Low Vcc Mute

When the supply voltage became lower than about 5.5V (Typ), The TB2996HQ operates the mute circuit automatically. This function prevents the large audible transient noise which is generated by low Vcc

### 9.2 Standby-Off Mute

The TB2996HQ operates the mute circuit during the standby-off transition. When the ripple voltage reached Vcc/5, the standby-off mute is terminated. The external mute has to be ON till the internal mute-OFF.

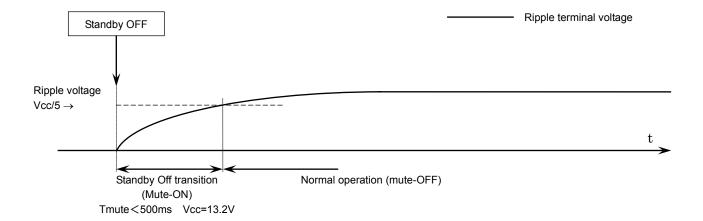


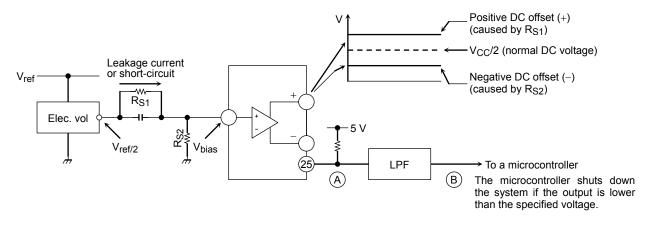
Figure 5 standby-Off Mute

# 10. Output DC Offset Detection

# 10.1 Offset circuit explanation

Offset Circuit This function detects the offset voltage between OUT(+) and OUT(-). The detection result is gotten by pin25.

The result of detection does not judge the abnormal offset or not. This function detects only the offset voltage which is decided by specification.



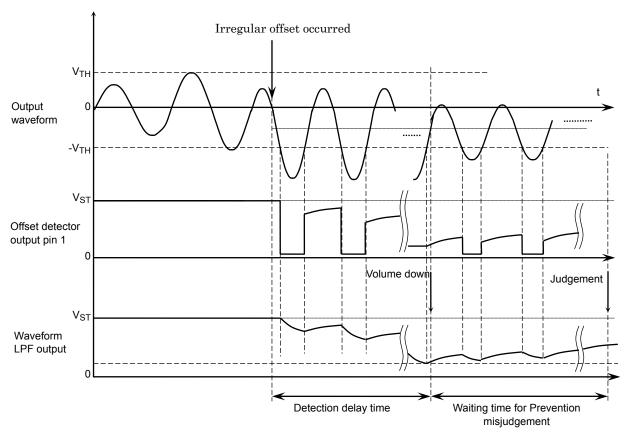


Figure 6 The detected result and audio output waveform

### 10.2 Outputshort detector

TB2996HQ has output shorting detector.

In case of shorting output to VCC/GND or over voltage power supplied, NPN transistor is turned on. In case of shorting output to output NPN Tr. is turned on and off in response to the input signal voltage.

### 11. Protection Functions

This product has internal protection circuits such as thermal shut down, over-voltage, out to VCC, out to GND, and out to out short circuit protections.

### (1) Thermal shut down

It operates when junction temperature exceeds 150°C (typ.).

When it operates, it is protected in the following order.

- 1. An Attenuation of an output starts first and the amount of attenuation also increases according to a temperature rising,
- 2. All outputs become in a mute state, when temperature continues rising in spite of output attenuation.
- 3. Shutdown function starts, when a temperature rise continues though all outputs are in a mute state.

In any case if temperature falls, it will return automatically.

### (2) Over-voltage

It operates when voltage exceeding operating range is supplied to  $V_{\rm CC}$  pin. If voltage falls, it will return automatically. When it operates, all outputs bias and high-side switch are turned off and all outputs are intercepted. Threshold voltage is  $23V({\rm Typ.})$ 

### (3) Short to Vcc, Short to GND, Output to output short

It operates when each output pin is in irregular connection and the load line goes over the SOA of power transistor (DMOS). When it operates, all outputs bias circuits are turned off and all outputs are intercepted. If irregular connection is canceled, it will return automatically.

Note 1: When the current phase shifts widely, the protection will operate for the capacitor etc are connected with the output. Please confirmation to use enough by using your testing board etc.

# 12. Absolute Maximum Ratings

(Ta = 25°C unless otherwise specified)

| Characteristics             | Condition | Symbol                  | Rating     | Unit |
|-----------------------------|-----------|-------------------------|------------|------|
| supply voltage (surge)      | max0.2s   | V <sub>CC</sub> (surge) | 50         | V    |
| supply voltage (DC)         |           | V <sub>CC (DC)</sub>    | 25         | ٧    |
| supply voltage (operation)  |           | V <sub>CC (opr)</sub>   | 18         | ٧    |
| output current (peak)       |           | I <sub>O (peak)</sub>   | 9          | Α    |
| power dissipation           | (Note)    | $P_{D}$                 | 125        | W    |
| Operating temperature range |           | T <sub>opr</sub>        | -40 to 85  | °C   |
| Storage temperature         |           | T <sub>stg</sub>        | -55 to 150 | °C   |

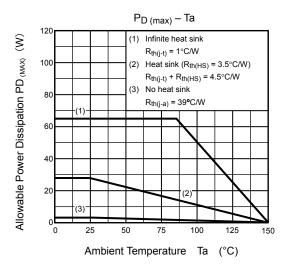
Note: Package thermal resistance  $R_{th(j-t)} = 1^{\circ}C/W$  (typ.) (Ta = 25°C, with infinite heat sink)

The absolute maximum ratings of a semiconductor device are a set of specified parameter values, which must not be exceeded during operation, even for an instant.

If any of these rating would be exceeded during operation, the device electrical characteristics may be irreparably altered and the reliability and lifetime of the device can no longer be guaranteed. Moreover, these operations with exceeded ratings may cause break down, damage, and/or degradation to any other equipment. Applications using the device should be designed such that each maximum rating will never be exceeded in any operating conditions.

Before using, creating, and/or producing designs, refer to and comply with the precautions and conditions set forth in this document.

### 12.1 Power Dissipation



# 13. Operating Ranges

| Characteristics | Symbol          | Condition          | Min | Тур | Max | Unit |
|-----------------|-----------------|--------------------|-----|-----|-----|------|
| Cumply valtage  | V <sub>CC</sub> | $R_L=4\Omega$      | 6   |     | 18  | ٧    |
| Supply voltage  |                 | R <sub>L</sub> =2Ω | 6   |     | 16  | V    |

# 14. Electrical Characteristics

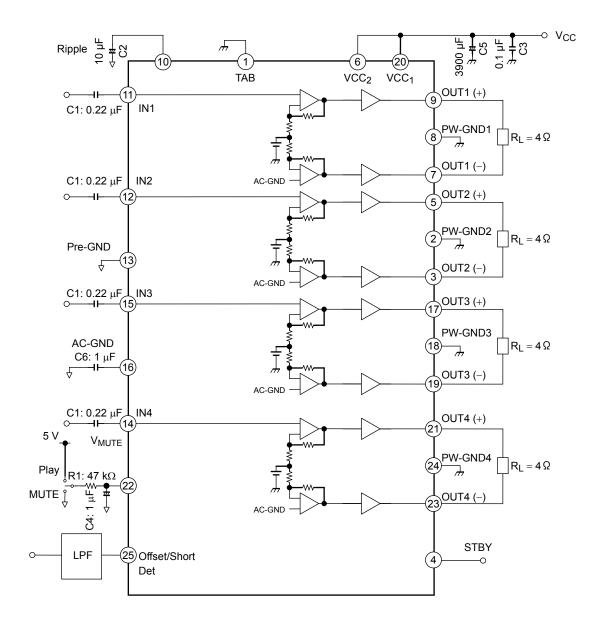
(VCC = 13.2 V, f = 1 kHz, RL = 4  $\Omega$ , Ta = 25°C unless otherwise specified)

| Characteristics                    | Symbol                   | Test Condition  | Min  | Тур.  | Max             | Unit |
|------------------------------------|--------------------------|---|------|-------|-----------------|------|
| Quiescent supply current           | Iccq                     | V <sub>IN</sub> = 0   | _    | 200   | 320             | mA   |
|                                    | P <sub>OUT</sub> MAX (1) | V <sub>CC</sub> = 15.2 V, MAX POWER                                   | _    | 49    | _               |      |
|                                    | P <sub>OUT</sub> MAX (2) | V <sub>CC</sub> = 14.4 V, MAX POWER                                   | _    | 44    | _               |      |
| Output power                       | P <sub>OUT</sub> MAX (3) | V <sub>CC</sub> = 13.7 V, MAX POWER                                   | _    | 40    | _               | W    |
|                                    | P <sub>OUT</sub> (1)     | V <sub>CC</sub> = 14.4 V, THD = 10%                                   | _    | 29    | _               |      |
|                                    | P <sub>OUT</sub> (2)     | THD = 10%   | 21   | 24    | _               |      |
|                                    | P <sub>OUT</sub> MAX (4) | V <sub>CC</sub> = 14.4 V, MAX POWER                                   | -    | 80    | _               |      |
| Output navor/P. =20)               | P <sub>OUT</sub> MAX (5) | V <sub>CC</sub> = 13.7 V, MAX POWER                                   | -    | 73    | _               | w    |
| Output power(R <sub>L</sub> =2Ω)   | P <sub>OUT</sub> (3)     | V <sub>CC</sub> = 14.4 V, THD = 10%                                   |      | 46    |                 | VV   |
|                                    | P <sub>OUT</sub> (4)     | THD = 10%   | -    | 45    | _               |      |
| Total harmonic distortion          | THD                      | P <sub>OUT</sub> = 4 W  | -    | 0.006 | 0.07            | %    |
| Voltage gain                       | G <sub>V</sub>           | V <sub>OUT</sub> = 0.775 Vrms   | 25   | 26    | 27              | dB   |
| Channel-to-channel voltage gain    | $\Delta G_V$             | V <sub>OUT</sub> = 0.775 Vrms   | -1.0 | 0     | 1.0             | dB   |
| Output noise voltage               | V <sub>NO</sub>          | Rg = 0 $\Omega$ , BW=20Hz to 20KHz                                    | _    | 50    | 70              | μV   |
| Ripple rejection ratio             | R.R.                     | $f_{RIP}$ = 100 Hz, Rg = 620 $\Omega$ (note1) $V_{RIP}$ = 0.775 Vrms  | 60   | 70    | _               | dB   |
| Crosstalk                          | C.T.                     | Po = 4W, $R_g = 620 \Omega$ ,   | _    | 80    | _               | dB   |
| Output offset voltage              | V <sub>OFFSET</sub>      | _   | -90  | 0     | 90              | mV   |
| Input resistance                   | R <sub>IN</sub>          | _   | _    | 90    | _               | kΩ   |
| Standby current                    | I <sub>STBY</sub>        | V <sub>STB</sub> = 0V,V22=0   | _    | 0.01  | 1               | μΑ   |
| Mute attenuation                   | ATT M                    | MUTE: ON $V_{OUT} = 7.75 \text{ Vrms} \rightarrow \text{MUTE: OFF}$   | 85   | 100   | _               | dB   |
| Ctandby control voltage            | V <sub>SB</sub> H        | POWER : ON  | 2.2  | _     | V <sub>CC</sub> | V    |
| Standby control voltage            | V <sub>SB</sub> L        | POWER : OFF   | 0    | _     | 0.9             | v    |
| Muto control voltage               | V <sub>M</sub> H         | MUTE : OFF  | 2.2  | _     | V <sub>CC</sub> | V    |
| Mute control voltage               | V <sub>M</sub> L         | MUTE : ON , $R_1 = 47 \text{ k}\Omega$                                | 0    | _     | 0.9             | V    |
| Offset detection threthold voltage | Vos <sub>det</sub>       | Rpull-up = 47 kΩ, +V= 5.0 V<br>Reference of Vout DC voltage           | ±1.0 | ±1.5  | ±2.0            | V    |
| Terminal 25 saturation voltage     | P25-Sat                  | Rpull-up = 10 k $\Omega$ , +V = 5.0 V<br>P25 is LOW at the detective. | _    | 100   | 500             | mV   |

Note 1 :  $f_{RIP}$  : repple frequency

Note2 :  $V_{RIP}$  : Ripple signal voltage ( AC fluctuations in the power supply )

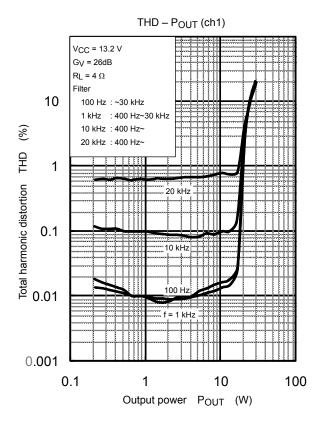
### 15. Test Circuit

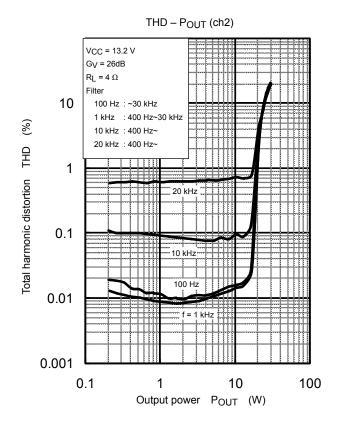


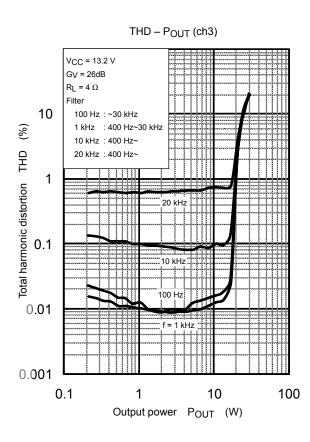
components in the test circuit are only used to determine the device characteristics. It is not guaranteed that the system will work properly with these components.

# 16. Electrical characteristics

# 16.1 Total Harmonic Distortion vs. Output Power







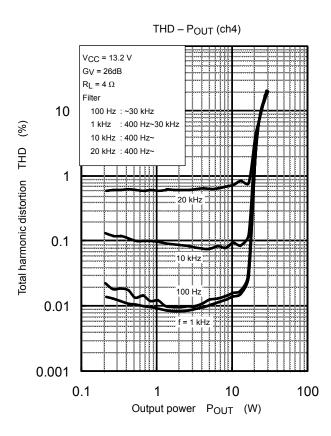


Fig. 7-1 Total Harmonic Distortion of Each Frequency ( $R_L=4\Omega$ ) 14

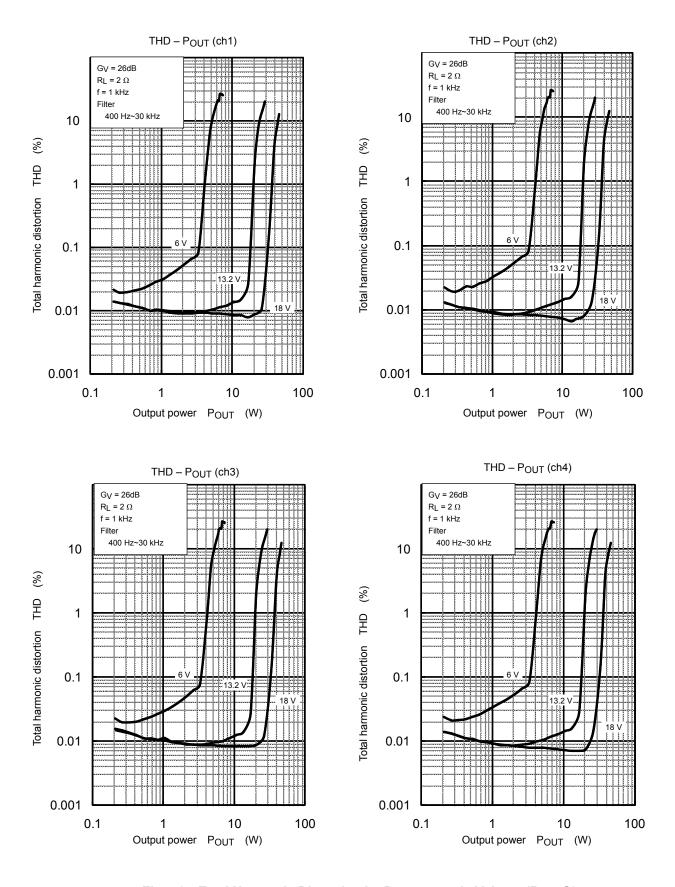


Fig.7-2 Total Harmonic Distortion by Power-supply Voltage ( $R_L$ =4 $\Omega$ )

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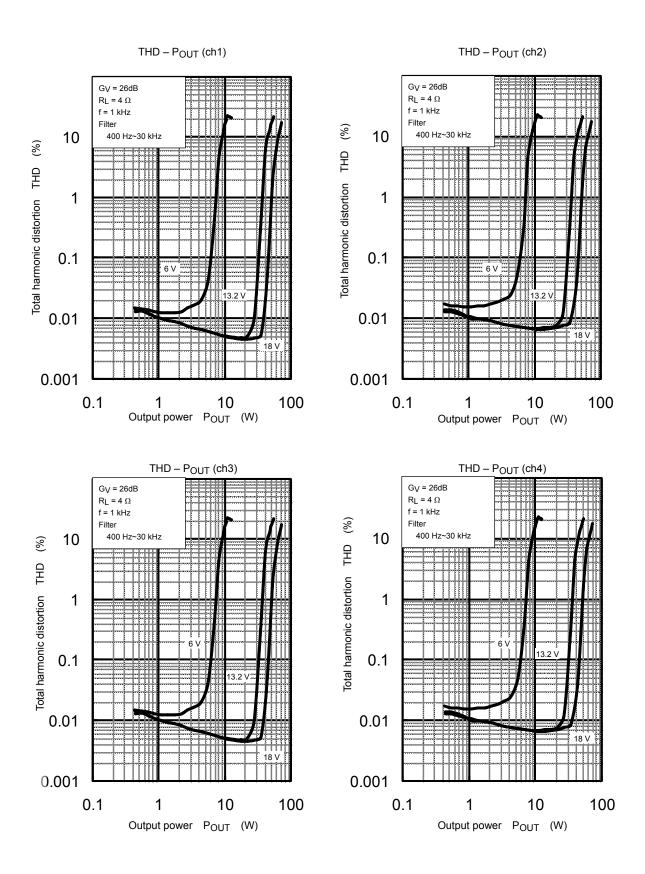


Fig.7-3 Total Harmonic Distortion by Power-supply Voltage ( $R_L$ =4 $\Omega$ )

# 16.2 Various Frequency Characteristics

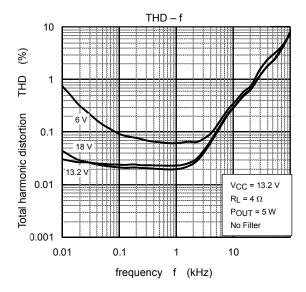


Fig.7-4 Frequency Characteristics of Total Harmonic Distortion

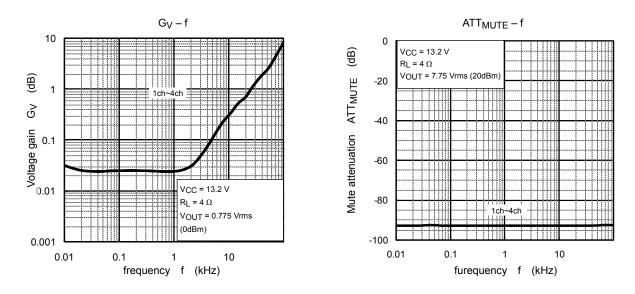


Fig. 7-5 Frequency Characteristics of Voltage Gain and Mute Attenuation

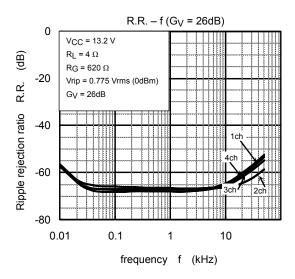
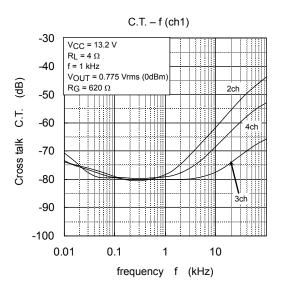
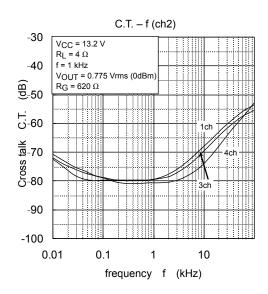
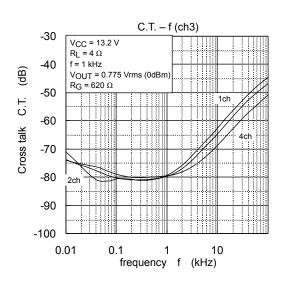


Fig. 7-6 Frequency Characteristics of Ripple Rejection Rate







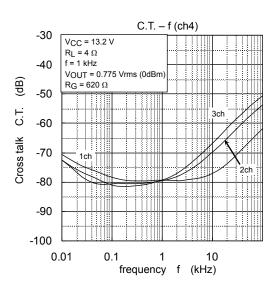
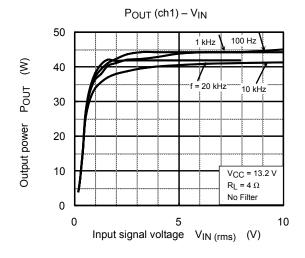
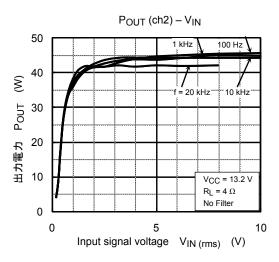
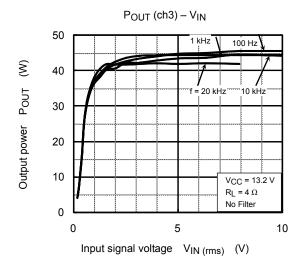


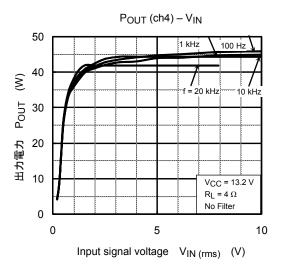
Fig. 7-7 Frequency Characteristics of Cross Talk

# 16.3 Output Power vs Input Voltage

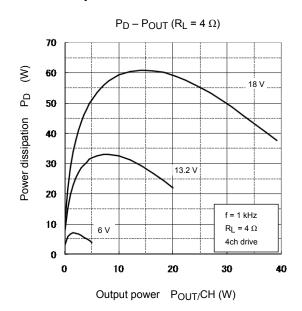




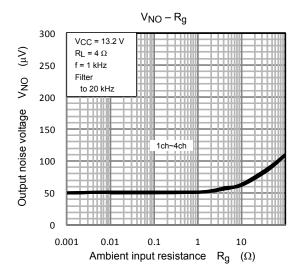


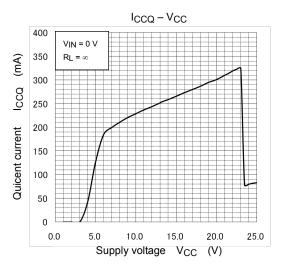


# 16.4 Power Dissipation vs. Output Power



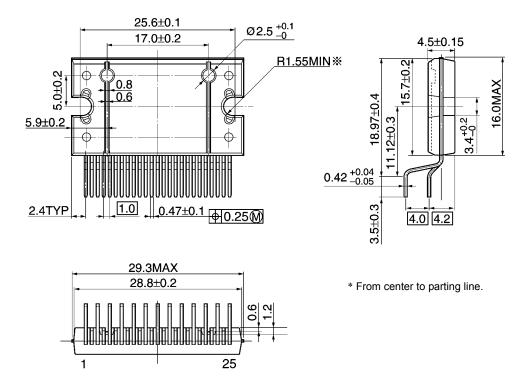
# 16.5 Other characteristics





# 17. Package Dimensions

HZIP25-P-1.00F Unit: mm



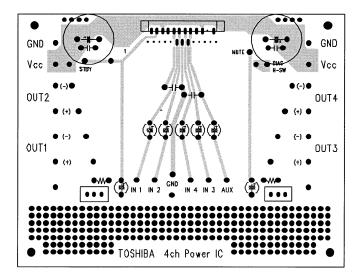
Weight: 7.7 g (typ.)

# 18. Board Layout for TOSHIBA 4-Channel Power Circuitry

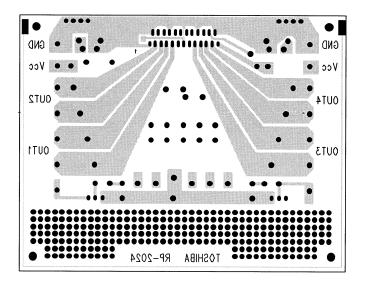
The layout diagrams below illustrate the front and back sides of the test board "RP-2024" for testing Toshiba's 4-channel power circuitry, which is housed in a HZIP25-P-1.00F (SPP25) package.

Note 1: This test board is designed to be used for several power amplifiers. Therefore, devices that are externally connected to the power amplifier to be tested must be checked before setting up the test board.

### Front Side



### **Back Side**



### Attention in Use

- Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of
  over current and/or IC failure. The IC will fully break down when used under conditions that exceed its
  absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs
  from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or
  ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings,
  such as fuse capacity, fusing time and insertion circuit location, are required.
- If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design
  to prevent device malfunction or breakdown caused by the current resulting from the inrush current at
  power ON or the negative current resulting from the back electromotive force at power OFF. For details on
  how to connect a protection circuit such as a current limiting resistor or back electromotive force adsorption
  diode, refer to individual IC datasheets or the IC databook. IC breakdown may cause injury, smoke or
  ignition.
- Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- Carefully select external components (such as inputs and negative feedback capacitors) and load
  components (such as speakers), for example, power amp and regulator. If there is a large amount of
  leakage current such as input or negative feedback condenser, the IC output DC voltage will increase. If
  this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure can
  cause smoke or ignition. (The over current can cause smoke or ignition from the IC itself.) In particular,
  please pay attention when using a Bridge Tied Load (BTL) connection type IC that inputs output DC voltage
  to a speaker directly.
- Over current Protection Circuit

Over current protection circuits (referred to as current limiter circuits) do not necessarily protect ICs under all circumstances. If the Over current protection circuits operate against the over current, clear the over current status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the over current protection circuit to not operate properly or IC breakdown before operation. In addition, depending on the method of use and usage conditions, if over current continues to flow for a long time after operation, the IC may generate heat resulting in breakdown.

### Thermal Shutdown Circuit

Thermal shutdown circuits do not necessarily protect ICs under all circumstances. If the Thermal shutdown circuits operate against the over temperature, clear the heat generation status immediately. Depending on the method of use and usage conditions, such as exceeding absolute maximum ratings can cause the thermal shutdown circuit to not operate properly or IC breakdown before operation.

### · Heat Radiation Design

When using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (Tj) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.

### Installation to Heat Sink

Please install the power IC to the heat sink not to apply excessive mechanical stress to the IC. Excessive mechanical stress can lead to package cracks, resulting in a reduction in reliability or breakdown of internal IC chip. In addition, depending on the IC, the use of silicon rubber may be prohibited. Check whether the use of silicon rubber is prohibited for the IC you intend to use, or not. For details of power IC heat radiation design and heat sink installation, refer to individual technical datasheets or IC databooks.

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